# **Interface structure and mechanical properties of AI203-20 vol % ZrO2-20 vol % SiCw ceramic composite**

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The microstructure, mechanical properties, fracture behaviour and toughening mechanisms of  $Al_2O_3$ -20 vol % ZrO<sub>2</sub> (2 mol %  $Y_2O_3$ )-20 vol % SiC<sub>w</sub> ceramic matrix composite were investigated by X-ray diffraction, scanning and transmission electron microscopies, energy dispersive analysis of X-rays, high-resolution electron microscopy techniques and three-point bending tests. The results show that the  $Al_2O_3$  matrix is simultaneously strengthened and toughened by both  $ZrO<sub>2</sub>$  particles and SiC whiskers. The interfacial amorphous layers between SiC whiskers and  $ZrO<sub>2</sub>$ , and  $Al<sub>2</sub>O<sub>3</sub>$  grains were observed by both TEM dark-field and high-resolution electron microscopy techniques.

## **1. Introduction**

The brittle nature of  $Al_2O_3$  ceramic, over the years, has prompted investigators to explore a variety of approaches to enhance its fracture toughness. The main approaches are incorporation of  $ZrO<sub>2</sub>$  particles and/or SiC whiskers  $[1-3]$ . The toughening is realized by tetragonal (t) to monoclinic (m)  $ZrO<sub>2</sub>$  phase transformation, whisker bridging and pull-out, and crack deflection. Many authors [4-5] have reported that the  $SiC_w-ZrO_2-Al_2O_3$  composites have superior mechanical and thermal properties compared with the monotonic Al<sub>2</sub>O<sub>3</sub> ceramic. Claussen *et al.* [6] concluded that the presence of SiC whiskers in  $SiC_w-ZrO_2-Al_2O_3$  composite could result in a larger transformation zone, due to stress transfer by the whisker, therefore generating a higher toughness. However, to date, reports on the interfacial structure between SiC whisker and ceramic matrix in  $SiC_w-ZrO_2-Al_2O_3$  composites are very few, and the interfacial characteristics have a strong influence on the toughening effects  $[7-9]$ . The object of this study was to assess the microstructure of  $Al_2O_3-20$  vol %  $ZrO_2$  (2 mol % Y<sub>2</sub>O<sub>3</sub>)-20 vol % SiC<sub>w</sub>, expecially, the structure and chemical composition of the interface, using high-resolution electron microscopy and energy dispersive analysis of X-rays (EDAX) techniques and their effect on the mechanical properties of the composite.

## **2. Experimental procedure**

The material used in this study was zirconiatoughened alumina  $(Al_2O_3 + 20 \text{ vol } \%$  ZrO<sub>2</sub> (2 mol %)  $Y_2O_3$ ) reinforced with 20 vol % SiC whiskers. Ultrafine alumina powders, having an average grain size of about 0.1  $\mu$ m, were proved to be  $\alpha$ -Al<sub>2</sub>O<sub>3</sub> by X-ray diffraction (XRD), and the chemical composition is shown in Table I. Ultrafine zirconia powders stabilized by 2 mol %  $Y_2O_3$  with an average particle size of 0.65  $\mu$ m contain nearly 34% tetragonal ZrO<sub>2</sub> and 66% monoclinic  $ZrO<sub>2</sub>$  and the chemical composition is shown in Table II. The  $\beta$ -SiC whiskers were supplied by Tokai Cabon. Japan, having a diameter of 0.5-1  $\mu$ m and a length of 30-60  $\mu$ m. The Al<sub>2</sub>O<sub>3</sub>-20 vol %  $ZrO_2$  (2 mol %  $Y_2O_3$ )-20 vol %  $SiC_w$  composite were hot-pressed at  $1650^{\circ}$ C for 1 h under a pressure of 25 MPa into 60 mm  $\times$  60 mm  $\times$  6 mm discs.

The density of the samples was measured by Archimedes' method in distilled water at  $20^{\circ}$ C. The percentage of t- $ZrO<sub>2</sub>$  in the total  $ZrO<sub>2</sub>$  was estimated by XRD on both the as-polished and the fractured surfaces.

Flexural strength and fracture toughness of the composite were measured in air at room temperature using an Instron 1186 machine. Flexural strength measurements were performed on bar specimens  $(3 \text{ mm} \times 4 \text{ mm} \times 36 \text{ mm})$  using a three-point bend fixture with a span of 30 mm. Fracture toughness measurements were performed on single-edge notched bar (SENB) specimens  $(2 \text{ mm} \times 4 \text{ mm} \times 25 \text{ mm})$  with a span of 16 mm, and a half-thickness notch was made using a diamond wafering blade, and  $K_{\text{IC}}$  values were determined using the method described elsewhere  $[4]$ .

Fracture surfaces of the composites were examined using a Hitachi S-570 scanning electron microscope.



Material	$\text{Al}_2\text{O}_3$	SiO <sub>2</sub> -4	Fe <sub>2</sub> O <sub>3</sub>	CaO	MgO	TiO,	НCl
$\text{Al}_2\text{O}_3$	99.66	0.01	< 0.01	< 0.01	0.01 >	0.01	⊂∪.2

TABLE II Chemical composition of  $ZrO<sub>2</sub>$  powders (wt %)



A Vickers hardness tester and an indentation load of 15 kg was used to introduce cracks into specimens for observing the crack propagation modes. The microstructure of the composite was characterized by TEM. Thin-foil specimens taken normal to the hot-pressing axis, were prepared by dimpling and subsequent ionbeam thinning and used to determine phase distribution and to identify possible interface reactions. In addition, a high-resolution phase-contrast imaging technique was employed in JEM-2000EX-II electron microscope to determine interface structure at atomic level resolution, and the distribution of chemical elements near the interface was measured by the EDAX technique.

## **3. Results and discussion**

The mechanical properties of  $Al_2O_3-20$  vol %  $ZrO_2$  $(2 \text{ mol } \% \text{ Y}_2\text{O}_3)$ -20 vol %SiC<sub>w</sub> composite are given in Table III. It can be seen that the fracture toughness of

TABLE III Room-temperature mechanical properties of the composite

Material	Flexural strength (MPa)	Fracture toughness, $(MPm^{1/2})$
$\rm SiC_w/ZrO_2/Al_2O_3$	$725 + 45$	$9.15 \pm 0.80$

the composite  $(9.15 \text{ MPa m}^{1/2})$  is higher than that of both 20 vol %  $ZrO_2$  (2 mol %  $Y_2O_3$ )-Al<sub>2</sub>O<sub>3</sub>  $(6.78 \text{ MPa m}^{1/2})$  and 20 vol % SiC<sub>w</sub>-Al<sub>2</sub>O<sub>3</sub> composite  $(6.54 \text{ MPa m}^{1/2})$ , and the flextural strength (725 MPa) is also higher than that of both 20 vol %  $ZrO<sub>2</sub>$  $(2 \text{ mol } \% \ Y_2O_3) - Al_2O_3$  (659 MPa) and 20 vol %  $SiC_w-Al<sub>2</sub>O<sub>3</sub>$  composite (592 MPa), indicating that the combination of  $ZrO<sub>2</sub>$  with SiC whisker has a better effect for improving the mechanical properties of the material and, particularly, the combination  $ZrO<sub>2</sub>$  with SiC whisker can result in a larger toughening response than simple additives.



*Figure 1* Fracture surfaces of  $SiC_w-ZrO_2$  (2Y)– $Al_2O_3$  composite.



*Figure 2* Scanning electron micrographs of indentation crack propagation paths in SiC<sub>w</sub>-ZrO<sub>2</sub> (2Y)-A1<sub>2</sub>O<sub>3</sub> composite. (a) Crack propagated along a whisker, (b) crack deflected by a whisker.



*Figure 3 XRD profiles of SiC<sub>w</sub>-ZrO<sub>2</sub> (2Y)-Al<sub>2</sub>O<sub>3</sub> composite. (a) Polished surface (70% m-ZrO<sub>2</sub>), (b) fractured surface (79% m-ZrO<sub>2</sub>)* 

The fracture surfaces of the composite obtained after flexural strength tests are shown in Fig. 1. It appeared to be quite rough with the pulled-out whiskers and the corresponding holes left by whiskers, indicating that the crack path had been strongly deflected by the reinforcing whiskers.

The fracture mechanisms of the composite can be demonstrated more clearly by examining the crack propagation produced by a Vickers indentation. The typical crack propagation paths are shown in Fig. 2. The arrows indicate the direction of crack propagation and the effect of the whiskers on the crack path is evident. Interfacial debonding, crack bridging and whisker pull-out were commonly observed along the crack paths.

The XRD results are shown in Fig. 3, indicating the appearance of dynamic  $t \rightarrow m$   $ZrO<sub>2</sub>$  phase transformation during fracturing, which also contributes to the fracture toughness.

A typical structure of the composite is shown in Fig. 4. The specimen was prepared by cutting a thin section from the hot-pressed disc normal to the



*Figure 4* Transmission electron micrograph of  $SiC_w-ZrO_2$ - $(2Y)$ -Al<sub>2</sub>O<sub>3</sub> composite showing preferential alignment of the whiskers in the hot-pressing plane and good bonding between the whisker and  $ZrO<sub>2</sub>$  (2Y)  $Al<sub>2</sub>O<sub>3</sub>$  ceramic.

pressing axis. The whiskers were seen along their axis and the serrated surfaces of the whiskers appeared to have a good bond with the  $ZrO<sub>2</sub>$  and  $Al<sub>2</sub>O<sub>3</sub>$  grains. The  $ZrO<sub>2</sub>$  at the interfacial regions shows the lath structure of monoclinic phase  $ZrO_2$  (2 mol %  $Y_2O_3$ ) transformed by the induction of residual thermal stresses due to the difference in thermal expansion coefficients of the SiC whisker and  $ZrO<sub>2</sub>$ . The stacking faults in the SiC whiskers could also be found from Fig. 4.

The microstructures of  $ZrO_2$  and  $Al_2O_3$  are shown in Fig. 5. The  $ZrO<sub>2</sub>$  particles are always located at the triple grain boundaries of  $Al_2O_3$ , except for a few  $ZrO<sub>2</sub>$  particles with very small grain sizes which exist within the  $Al_2O_3$  grains. These fine  $ZrO_2$  particles are always  $t$ - $ZrO<sub>2</sub>$  because their grain sizes are much smaller than the critical size for  $t \rightarrow m$  ZrO<sub>2</sub> transformation. The  $ZrO<sub>2</sub>$  particles within the  $Al<sub>2</sub>O<sub>3</sub>$  grains strengthen the matrix, due to the induction of many dislocations in  $Al_2O_3$  grains caused by elastic and thermal mismatch between  $ZrO<sub>2</sub>$  and  $Al<sub>2</sub>O<sub>3</sub>$ . The microcracks at  $Al<sub>2</sub>O<sub>3</sub>$  grain boundaries can also be found in Fig. 5d, which are caused by  $t \rightarrow m$  ZrO<sub>2</sub>



*Figure 5* Transmission electron micrographs of  $ZrO_2$  (2Y) and  $Al_2O_3$  in  $SiC_w-ZrO_2$  (2Y)- $Al_2O_3$  composite showing (a) that the  $ZrO_2$ particles are always located at the triple grain boundaries of  $A1_2O_3$ , (b) that the  $ZrO_2$  particles with small grain size exist in the  $A1_2O_3$  grain, (c) the hexagonal network of dislocations in an  $Al_2O_3$  grain, and (d) that the dislocation was pinned by  $ZrO_2$  particles.



*Figure* 6 Transmission electron micrographs of the SiC<sub>w</sub>-Al<sub>2</sub>O<sub>3</sub> interface. (a) Bright-field image showing that the Al<sub>2</sub>O<sub>3</sub> grains have a good bond with the SiC whiskers. (b) Dark-field image formed with diffusely scattered electron showing a thin layer of amorphous phase at the interface.



*Figure 7* Transmission electron micrographs of the SiC<sub>w</sub>-ZrO<sub>2</sub> interface. (a) Bright-field image showing that the ZrO<sub>2</sub> grains have a good bond with the SiC whiskers. (b) Dark-field image formed with diffusely scattered electron showing a thin layer of amorphous phase at the interface.

phase transformation during cooling after hot pressing. All these factors will affect the final mechanical properties of the composite.

In regions of intimate contact between the SiC whiskers and the  $Al_2O_3$  grains (Fig. 6a), the  $Al_2O_3$ grains have a good bond with the SiC whiskers. The dark-field image, taken with diffusely scattered electrons, highlighted a thin layer of amorphous phase at the  $Al_2O_3-SiC$  interface (arrowed in Fig. 6b). Similarly, the  $ZrO<sub>2</sub>$  grains and SiC whiskers are also separated by a thin layer of amorphous phase, as shown in Fig. 7. The stability of the SiC whiskers in the composite was confirmed by the X-ray diffraction spectrum (Fig. 8), which showed only the SiC,  $ZrO<sub>2</sub>$ and  $Al<sub>2</sub>O<sub>3</sub>$  reflections.

The results of EDAX chemical analyses performed on interfaces between SiC whiskers and  $ZrO<sub>2</sub>$ ,  $Al<sub>2</sub>O<sub>3</sub>$  grains are shown in Fig. 9. For two kinds of interfaces, the silicon content on the SiC side is over 95wt% and there is little zirconium, yttrium and aluminium due to the ion thining. However, the yttrium content on the  $ZrO<sub>2</sub>$  side is higher than that in the original  $ZrO_2$  (2 mol %  $Y_2O_3$ ) powders and there is very small amount of silicon on the  $ZrO<sub>2</sub>$  side near the interface, indicating the mixture diffusion between  $ZrO_2$  and  $Al_2O_3$ . Ricoult's [10] study on the oxidation of  $ZrO_2-Al_2O_3$ composite indicates that oxygen atoms react with SiC, forming  $SiO<sub>2</sub>$  amorphous phase and graphitic carbon.



*Figure 8 X-ray diffraction spectrum of*  $SiC_w-ZrO_2$  *(2Y)-Al<sub>2</sub>O<sub>3</sub>* composite showing only ( $\otimes$ ) SiC<sub>w</sub>, ( $\odot$ ) ZrO<sub>2</sub> and ( $\bullet$ ) Al<sub>2</sub>O<sub>3</sub> reflections.



*Figure 9* EDAX chemical analyses performed on the interfaces. (a)  $SiC_w-Al_2O_3$  interface, (b)  $SiC_w-ZrO_2$  interface.

A typical HREM image of the interface is shown in Fig. 10, indicating that  $Al_2O_3$  and SiC are separated by a layer of amorphous phase with a thickness of nearly 10 nm (Fig. 10a). The  $ZrO_2/SiC_w$  interface also has an amorphous layer, as shown in Fig. 10b. It can also be found that the amorphous layer at the  $Al_2O_3-SiC_w$  interface is thicker than that at  $ZrO<sub>2</sub>-SiC<sub>w</sub>$ . The chemical composition and formation mechanism of the interfacial amorphous layer will be investigated in more detail.

The presence of the amorphous phase at the whisker/ceramic interface evidently increased the



*Figure 10* HREM images of  $SiC_w-ZrO_2$  (2Y)- $Al_2O_3$  composite. (a)  $SiC_w-Al_2O_3$  interface, (b)  $SiC_w-ZrO_2$  interface.

bonding strength and hence inhibited the pull-out of whiskers, resulting in a lower fracture toughness. Many researchers [5, 11] have reported that the presence of the interfacial amorphous layer inhibited the toughening effects of SiC whiskers. The amorphous layer at the interface may be caused by the  $Y_2O_3$ sintering aid and the light-element enrichment on the surface of the as-received whiskers. Yang and Stevens [8] have reported that the interfacial amorphous phases were virtually eliminated when the whiskers were leached with an acid before being incorporated into the matrix. As shown in Figs 1 and 2, both the numbers and length of pulled-out whiskers are limited, which are directly affected by the interfacial amorphous layer. Therefore, the pre-treatment of whiskers may be one of the effective approaches to eliminate the interracial amorphous phases between SiC whiskers and the ceramic matrix for improving the fracture toughness of the composites.

#### **4. Conclusions**

 $(b)$ 

1. The combination of  $ZrO<sub>2</sub>$  with SiC whisker has a good effect for improving the mechanical properties of  $Al_2O_3$  matrix. The main toughening mechanisms of the composite are crack deflection, whisker bridging,

whisker pull-out and  $t \rightarrow m ZrO_2$  phase transforma**tion.** 

2. SiC whiskers and  $ZrO_2$ ,  $Al_2O_3$  grains are separ**ated by an interracial layer of amorphous phase, which inhibit the pull-out of whiskers.** 

**3. Elemental mixture diffusion occurs between**   $ZrO_2$  and  $Al_2O_3$  grains in  $SiC_w-ZrO_2-Al_2O_3$  com**posites.** 

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